

ST13005

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Switch mode power supplies

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

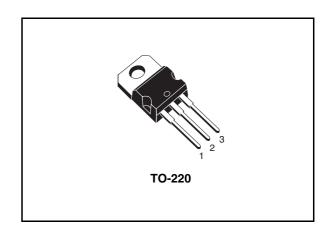


Figure 1. Internal schematic diagram

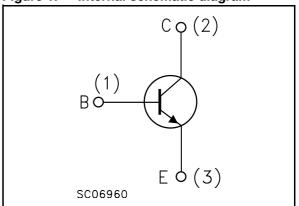


Table 1. Device summary

Order code	Marking ⁽¹⁾	Package	Packaging
ST13005	13005A	TO-220	Tube
ST13005	13005B	TO-220	Tube

^{1.} Product is pre-selected in DC current gain (group A and group B). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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ST13005 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	9	V
I _C	Collector current	4	Α
I _{CM}	Collector peak current (t _P < 5ms)	8	Α
I _B	Base current	2	Α
I _{BM}	Base peak current (t _P < 5ms)	4	Α
P _{tot}	Total dissipation at T _c = 25°C	75	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Electrical characteristics ST13005

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test Co	nditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current	V _{CE} =700 V				1	mA
OLS	$(V_{BE} = 0)$	V _{CE} =700 V	$T_C = 125^{\circ}C$			5	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 9 V				1	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C =10 mA		400			V
	0 11 1	I _C = 1 A	$I_B = 0.2 A$			0.5	V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 2 A$	$I_{B} = 0.5 A$			0.6	V
	odiaration voltage	$I_C = 4 A$	$I_B = 1 A$			1	V
V _{BE(sat)} (1)	Base-emitter saturation	I _C = 1 A	$I_B = 0.2 A$			1.2	V
VBE(sat)	voltage	$I_C = 2 A$	$I_{B} = 0.5 A$			1.6	V
		I _C = 1 A	V _{CE} = 5 V				
h _{FE} (1)(2)	DC current gain	Group A		15		32	
''FE`''	Do current gain	Group B		27		45	
		$I_C = 2 A$	$V_{CE} = 5 V$	8		40	
	Resistive load	I _C = 2 A	V _{CC} = 125 V				
t _s	Storage time	$I_{B1} = -I_{B2} = 0$).4 A	1.5		3	μs
t _f	Fall time	t _p = 30 μs			0.2		μs

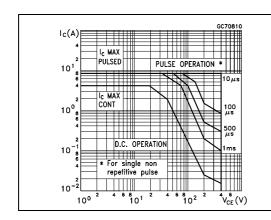
^{1.} Pulsed duration = 300 ms, duty cycle £1.5%

^{2.} Product is pre-selected in DC current gain (group A and group B). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



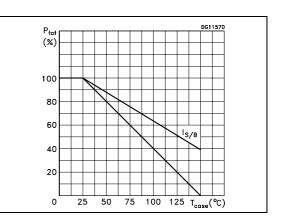
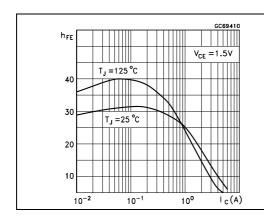


Figure 4. DC current gain

Figure 5. DC current gain



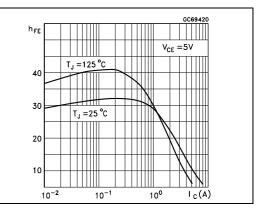
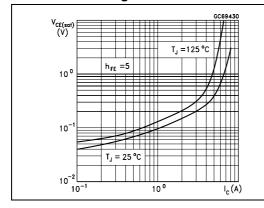
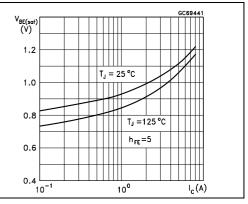


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage





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Electrical characteristics ST13005

Figure 8. Inductive load fall time

Figure 9. Inductive load storage time

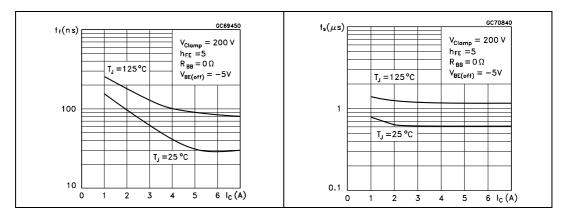


Figure 10. Resistive load fall time

Figure 11. Resistive load storage time

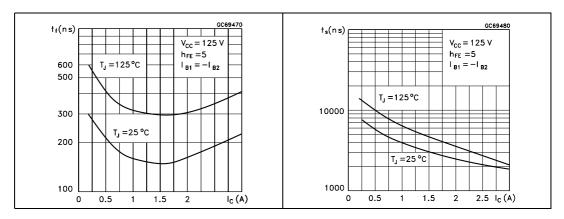
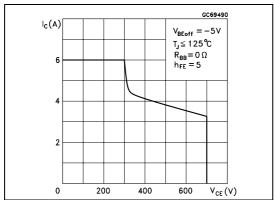


Figure 12. Reverse biased operating area



ST13005 Test circuit

3 Test circuit

Figure 13. Inductive load switching test circuit

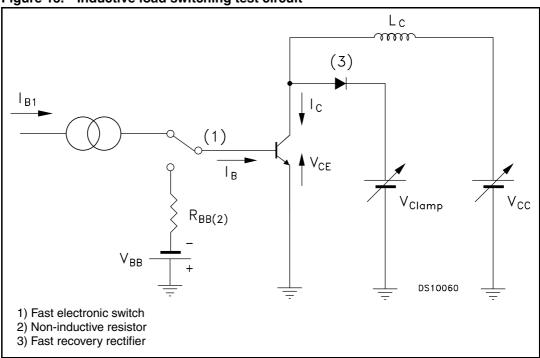
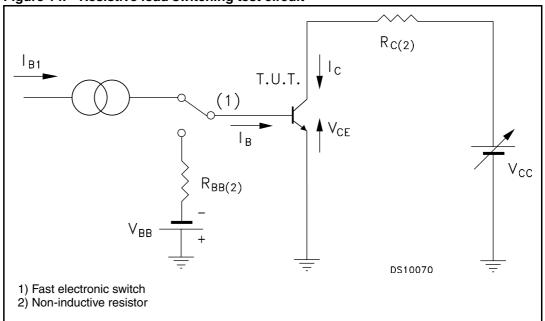


Figure 14. Resistive load switching test circuit

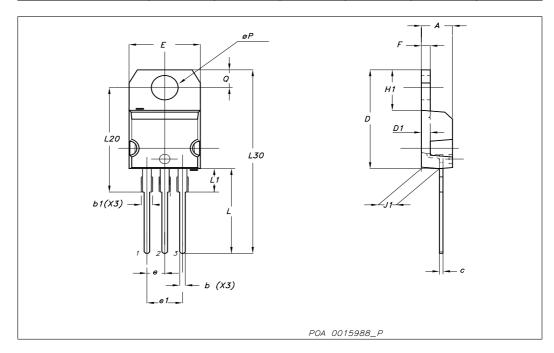


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 mechanical data

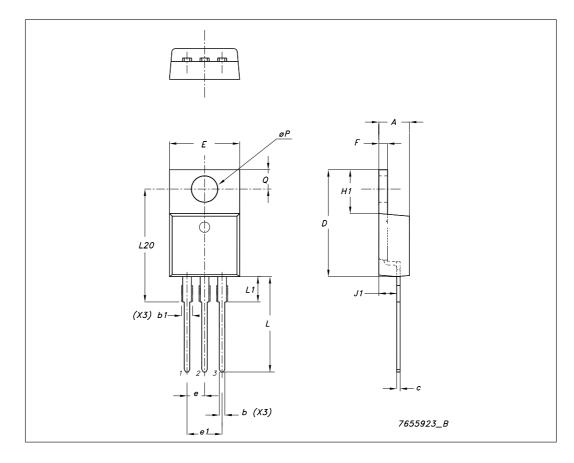
Di	mm			inch		
Dim	Min	Тур	Max	Min	Тур	Max
Α	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
Е	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
ØP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



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	TO-220	(option 1) mechanical	data
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Dim	mm				
DIM	Min	Тур	Max		
Α	4.47		4.67		
b	0.70		0.91		
b1	1.17		1.37		
С	0.31		0.53		
D	14.60		15.70		
Е	9.96		10.36		
е		2.54			
e1	4.98	5.08	5.18		
F	1.17		1.37		
H1	6.10		6.80		
J1	2.52		2.82		
L	12.70		13.80		
L1	3.20		3.96		
L20	15.21		16.77		
øΡ	3.73		3.94		
Q	2.59		2.89		



ST13005 Revision history

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
21-Jun-2004	6	
22-Aug-2007	7	Updated mechanical data <i>on page 10</i> according to PCN APM-PWR/07/2804
12-Oct-2007	8	Updated marking in <i>Table 1</i>

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